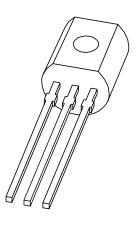
DISCRETE SEMICONDUCTORS

DATA SHEET



BC549; BC550 NPN general purpose transistors

Product data sheet Supersedes data of 1999 Apr 22 2004 Oct 11



NPN general purpose transistors

BC549; BC550

FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 45 V).

APPLICATIONS

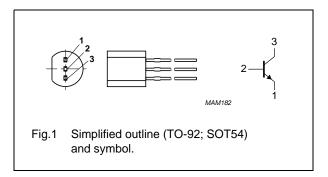
• Low noise stages in audio frequency equipment.

DESCRIPTION

NPN transistor in a TO-92; SOT54 plastic package. PNP complements: BC559 and BC560.

PINNING

PIN	DESCRIPTION	
1	emitter	
2	base	
3	collector	



ORDERING INFORMATION

TYPE NUMBER		PACKAGE			
TIPE NOMBER	NAME	DESCRIPTION	VERSION		
BC549C	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54		
BC550C					

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter			
	BC549		_	30	V
	BC550		_	50	V
V_{CEO}	collector-emitter voltage	open base			
	BC549		_	30	V
	BC550		_	45	V
V _{EBO}	emitter-base voltage	open collector	_	5	V
I _C	collector current (DC)		_	100	mA
I _{CM}	peak collector current		_	200	mA
I _{BM}	peak base current		_	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	500	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		_	150	°C
T _{amb}	ambient temperature		-65	+150	°C

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Note

1. Transistor mounted on an FR4 printed-circuit board.

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	250	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 30 V; I _E = 0 A	_	_	15	nA
		$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$	_	_	5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 5 V; see Fig.2				
		I _C = 10 μA	-	270	_	
		$I_C = 2 \text{ mA}$	420	520	800	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	90	250	mV
		$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	-	200	600	mV
V _{BEsat}	base-emitter saturation voltage	$I_C = 10 \text{ mA}$; $I_B = 0.5 \text{ mA}$; note 1	_	700	_	mV
		$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}; \text{ note 1}$	-	900	_	mV
V_{BE}	base-emitter voltage	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}; \text{ note } 2$	580	660	700	mV
		$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}; \text{ note } 2$	_	_	770	mV
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	_	1.5	_	pF
C _e	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_C = I_c = 0 \text{ A};$ f = 1 MHz	-	11	_	pF
f _T	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA};$ f = 100 MHz	100	-	_	MHz
F	noise figure	$V_{CE} = 5 \text{ V}; I_{C} = 200 \mu\text{A};$ $R_{S} = 2 k\Omega; f = 10 \text{ Hz to } 15.7 \text{ kHz}$	-	-	4	dB
		$V_{CE} = 5 \text{ V; } I_{C} = 200 \mu\text{A;}$ $R_{S} = 2 k\Omega; f = 1 \text{ kHz; } B = 200 \text{ Hz}$	-	-	4	dB

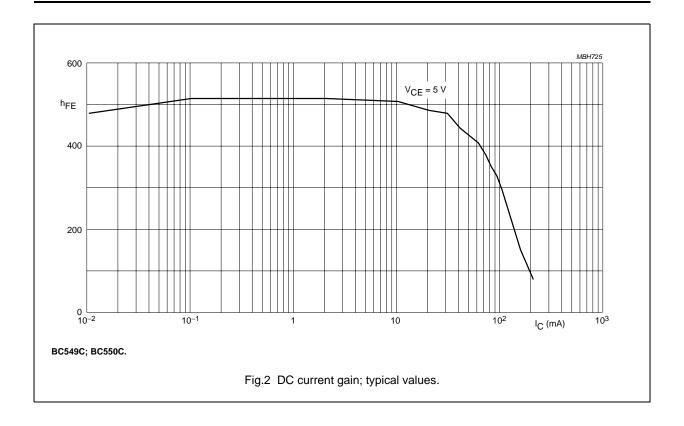
Notes

- 1. V_{BEsat} decreases by about 1.7 mV/K with increasing temperature.
- 2. V_{BE} decreases by about 2 mV/K with increasing temperature.

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NPN general purpose transistors

BC549; BC550



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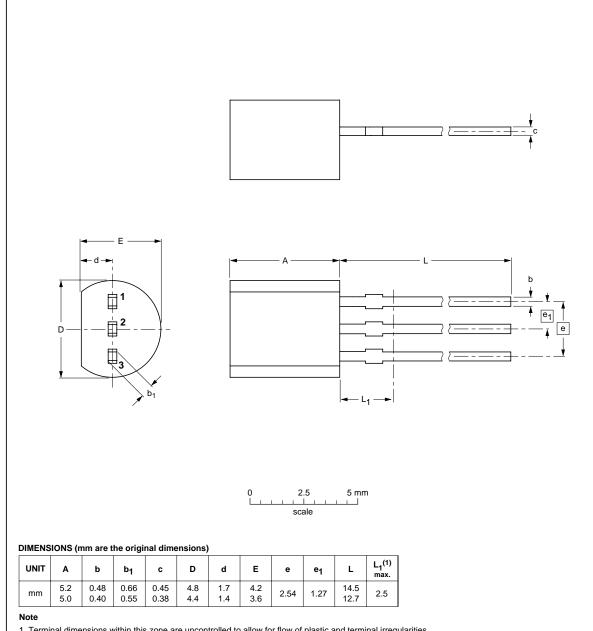
NPN general purpose transistors

BC549; BC550

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFERENCES		EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT54		TO-92	SC-43A		-04-06-28 04-11-16	

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NPN general purpose transistors

BC549; BC550

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
- 2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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Printed in The Netherlands R75/04/pp7 Date of release: 2004 Oct 11 Document order number: 9397 750 13569

